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# Linear IC Converter cmos

# A/D Converter

(With 4-channel Input at 12-bit Resolution)

# MB88101A

#### ■ DESCRIPTION

The MB88101A is an analog-to-digital converter that converts its analog input to a 12-bit digital value and outputs it as serial data.

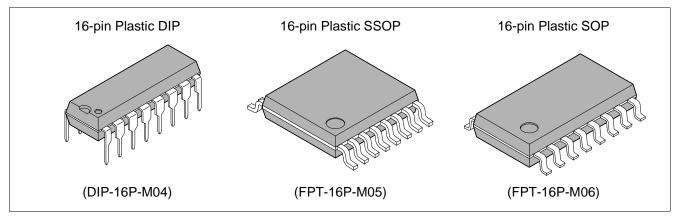
The MB88101A employs a successive approximation method for A/D conversion.

The MB88101A has four input channels selectable for analog input under control of the dedicated external pins. The MB88101A can be switched to a mode for continuous A/D conversion, in which it outputs serial data from the MSB or LSB selectable depending on the mode setting.

#### **■ FEATURES**

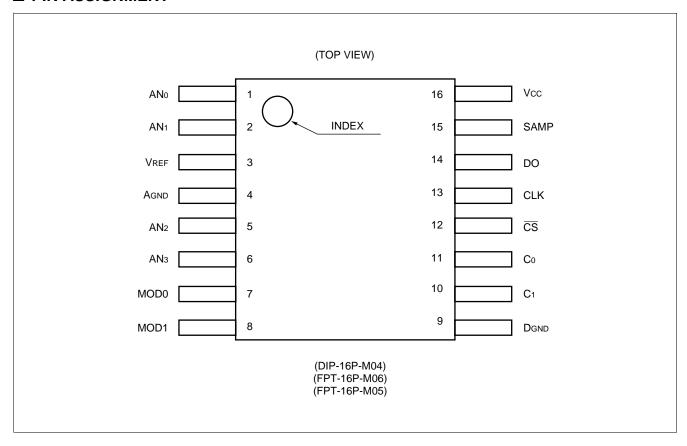
- 4-channel analog input
- One analog input channel selectable for conversion by external control
- CR-type successive approximation system with a sample-and-hole circuit
- 12-bit resolution
- · Serial output of 12-bit digital data
- Capable of continuous conversion (continuous conversion mode)
- MSB or LSB selectable for serial output
- CMOS process
- Package options of 16-pin DIP, 16-pin SSOP, and 16-pin SOP available

#### **■ PACKAGES**





### **■ PIN ASSIGNMENT**



### **■ PIN DESCRIPTION**

| Pin no.          | Symbol   | I/O | Descriptions   |  |
|------------------|--|-----|--|--|
| 1<br>2<br>5<br>6 | AN <sub>0</sub><br>AN <sub>1</sub><br>AN <sub>2</sub><br>AN <sub>3</sub> | I   | Analog input pins. One of these channels can be selected depending on the $C_0$ and $C_1$ settings.  |  |
| 14               | DO   | 0   | This pin outputs the result of A/D conversion. The result is 12-bit serial data output in synchronization with the rise of CLK.  |  |
| 13               | CLK  | I   | Clock input pin for A/D conversion   |  |
| 12               | CS   | I   | Chip select signal input pin. Setting the signal level to "L" after turning the power on starts A/D conversion; setting it to "H" stops A/D conversion. When this pin is "H", the DO and SAMP pins are "Hi-Z".   |  |
| 11<br>10         | C <sub>0</sub><br>C <sub>1</sub>   | I   | Input pins for selecting the analog input channels from among pins ANo to AN3. See Table 1 for the correspondence between the pin settings and the channels selected. To switch the channel in mode 2 or 3, set these pins before the SAMP pin goes "H". |  |
| 7<br>8           | MOD0<br>MOD1   | I   | Conversion mode setting pins. For the correspondence between the pin settings and the modes selected, see Table 2 and "■ FUNCTIONAL DESCRIPTION."  |  |
| 15               | SAMP   | 0   | This pin becomes active in prior to data output. Serial data is output from the DO pin five clock cycles after the signal level at this pin goes "L" after "H" for one clock cycle.  |  |
| 3                | VREF   | _   | Reference voltage input pin  |  |
| 4                | Agnd   | _   | Analog circuit ground pin  |  |
| 9                | DGND   | _   | Digital circuit ground pin   |  |
| 16               | Vcc  | _   | Power supply pin   |  |

Hi-Z : High-Z

#### • Channel selection

### Table 1 Pin Settings and Channel Selection

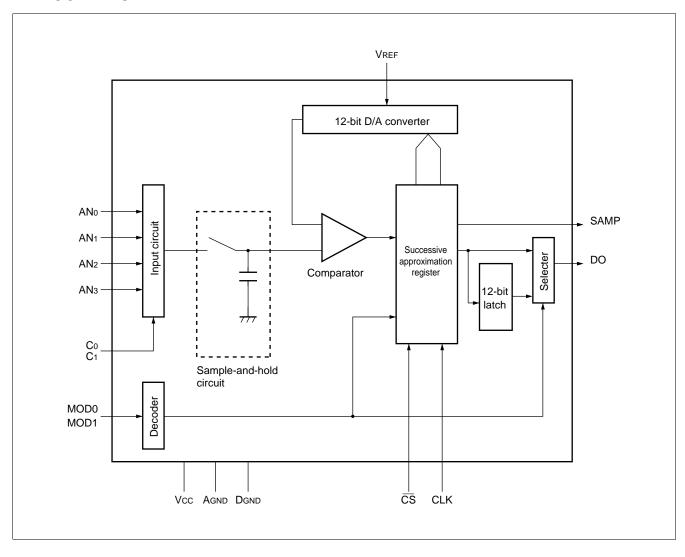
| <b>C</b> <sub>1</sub> | C <sub>0</sub> | Channel         |
|-----------------------|----------------|-----------------|
| L                     | L              | AN <sub>0</sub> |
| L                     | Н              | AN <sub>1</sub> |
| Н                     | L              | AN <sub>2</sub> |
| Н                     | Н              | AN <sub>3</sub> |

#### • Mode selection

Table 2 Pin Settings and Mode Selection

| MOD 0 | MOD1 | Mode       |
|-------|------|------------|
| L     | L    | Mode 1     |
| L     | Н    | Mode 2     |
| Н     | L    | (Disabled) |
| Н     | Н    | Mode 3     |

### **■ BLOCK DIAGRAM**

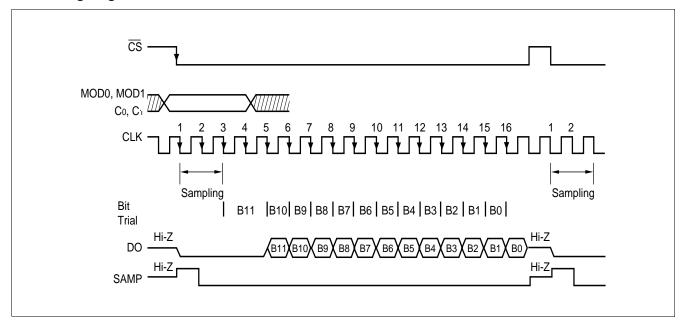


#### **■ FUNCTIONAL DESCRIPTION**

#### 1. Mode 1

This mode sets the DO pin to "L" and stops conversion upon completion of conversion of 12 bits. To restart conversion, set  $\overline{\text{CS}}$  to "H" once then to "L". In this mode, converted data is output from the MSB.

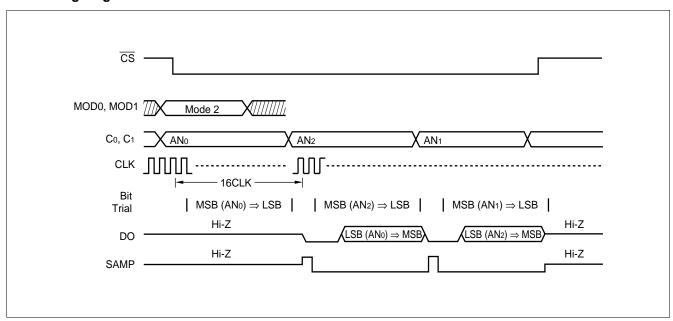
#### • Timing diagram



### 2. Mode 2

This mode continues conversion until  $\overline{CS}$  becomes "H" after it becomes "L". Converted data is output from the LSB, with the first piece of converted data output 20 clock cycles after  $\overline{CS}$  becomes "L". Changing the channel select pin settings before starting sampling of one analog input allows another to be converted.

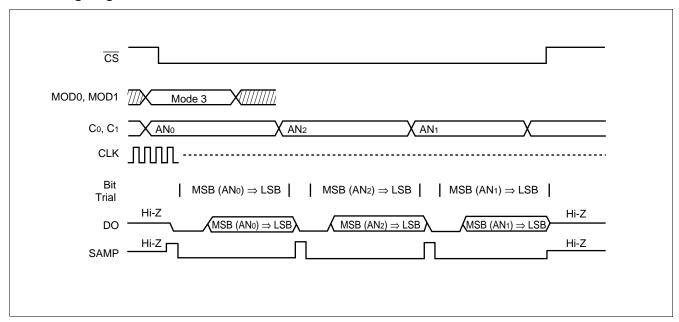
#### Timing diagram



#### 3. Mode 3

This mode continues conversion until  $\overline{\text{CS}}$  becomes "H" after it becomes "L". Converted data is output from the MSB. Changing the channel select pin settings before starting sampling of one analog input allows another to be converted.

### • Timing diagram



#### ■ ABSOLUTE MAXIMUM RATINGS

| Parameter             | Symbol           | Conditions   | Rat   | Unit      |       |
|-----------------------|------------------|--------------|-------|-----------|-------|
| raiailletei           | Syllibol         | Conditions   | Min   | Max       | Offic |
| Power supply voltage  | Vcc              |              | -0.3  | +7.0      | V     |
| Fower supply voltage  | V <sub>REF</sub> | Based on GND | -0.3* | +7.0*     | V     |
| Input voltage         | Vin              | (Ta = +25°C) | -0.3  | Vcc + 0.3 | V     |
| Output voltage        | Vouт             |              | -0.3  | Vcc + 0.3 | V     |
| Power consumption     | PD               | _            | _     | 150       | mW    |
| Operating temperature | Та               | _            | -40   | +85       | °C    |
| Storage temperature   | Tstg             | _            | -55   | +150      | °C    |

<sup>\*:</sup>  $V_{CC} \ge V_{REF}$ 

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

#### ■ RECOMMENDED OPERATING CONDITIONS

| Parameter             | Symbol | Value |     |     |      |  |
|-----------------------|--------|-------|-----|-----|------|--|
| Parameter             | Symbol | Min   | Тур | Max | Unit |  |
| Power supply voltage  | Vcc    | 3.3   | _   | 5.5 | V    |  |
| Fower supply voltage  | GND    | _     | 0   | _   | V    |  |
| Operation temperature | Та     | -40   | _   | +85 | °C   |  |

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

### **■ ELECTRICAL CHARACTERISTIC**

#### 1. DC Characteristics

#### (1) Digital section

 $(Vcc = 3.3 \text{ V to } 5.5 \text{ V}, D_{GND} = 0 \text{ V}, Ta = -40^{\circ}\text{C to } +85^{\circ}\text{C})$ 

| Parameter                             | Symbol | Pin name                         | Conditions                                    |              | Value |                       | Unit  |         |   |
|---------------------------------------|--------|----------------------------------|---|--------------|-------|-----------------------|-------|---------|---|
| Parameter                             | Symbol | riii iiaiiie                     | Conditions                                    | Min          | Тур   | Max                   | J.III |         |   |
| Power supply voltage                  | Vcc    |                                  | _   | 3.3          | 5.0   | 5.5                   | V     |         |   |
| Power supply current                  | Icc    | Vcc                              | Operation at<br>CLK =166kHz<br>(with no load) | _            | 0.8   | 2.0                   | mA    |         |   |
| Input leakage current                 | IILK   | MOD0,                            | V <sub>IN</sub> = 0 to V <sub>CC</sub>        | -10          | _     | 10                    | μΑ    |         |   |
| Low-level input voltage               | VıL    | MOD1<br>CLK<br>CS                |   | CLK          | _     | V <sub>SS</sub> - 0.3 | _     | 0.2 Vcc | V |
| High-level input voltage              | VIH    | C <sub>0</sub><br>C <sub>1</sub> | _   | 0.8 Vcc      | _     | Vcc+<br>0.3           | V     |         |   |
| High-impedance output leakage current | louz   | DO<br>SAMP                       | V <sub>IN</sub> = 0 to V <sub>CC</sub>        | -10          | _     | 10                    | μА    |         |   |
| Low-level output voltage              | Vol    |                                  | IoL = 2.5 mA                                  | _            | _     | 0.4                   | V     |         |   |
| High-level output voltage             | Vон    |                                  | Іон = -400 μА                                 | Vcc -<br>0.4 | _     | _                     | V     |         |   |

#### (2) Analog section

(VREF, VCC = 3.3 V to 5.5 V (VCC  $\geq$  VREF), AGND = 0 V, Ta =  $-40^{\circ}$ C to  $+85^{\circ}$ C)

| Parameter                    | Symbol | Pin name               | Value |     |                  | Unit  |
|------------------------------|--------|------------------------|-------|-----|------------------|-------|
| Farameter                    | Symbol | Fili lialile           | Min   | Тур | Max              | Ollit |
| Resolution                   | _      |                        | _     | 12  | _                | bit   |
| Linearity error              | _      | ANo to AN3             | -4.0  | _   | 2.0              | LSB   |
| Differential linearity error | _      |                        | -1.0  | _   | 3.0              | LSB   |
| Conversion time              | _      | _                      | _     | 16  | _                | CLK   |
| Consumption current          | IREF   | Vref                   | _     | 100 | 300              | μΑ    |
| Analog reference voltage     | _      | VREF                   | 3.3   | 5.0 | Vcc              | V     |
| Analog input voltage         | _      | ANo to AN <sub>3</sub> | 0     | _   | V <sub>REF</sub> | V     |

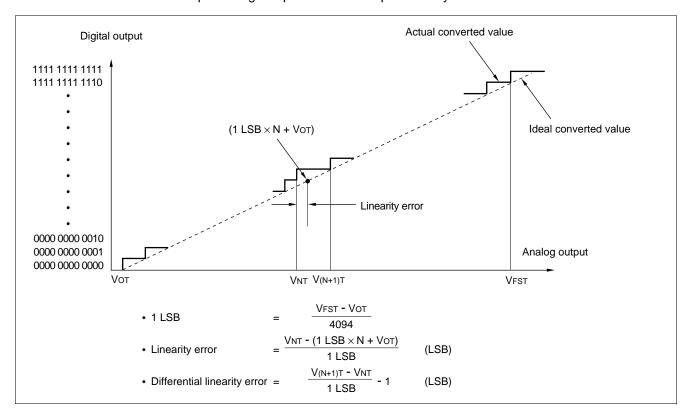
#### (3) Definitions of A/D converter terms

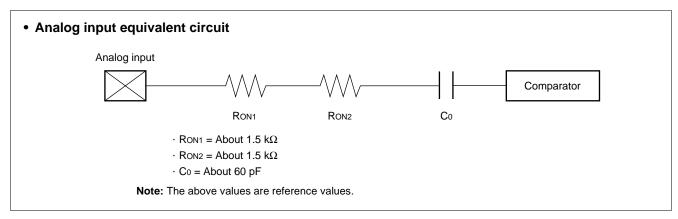
- Resolution
  - Analog transition identifiable by the A/D converter
- · Linearity error

Deviation of the straight line drawn between the zero transition point (0000 0000 0000  $\leftrightarrow$  0000 0000 0001) and the full-scale transition point (1111 1111 1110  $\leftrightarrow$  1111 1111) of the device from actual conversion characteristics

· Differential linearity error

Deviation from the ideal input voltage required to shift output code by one LSB





Notes: • The tolerance of output impedance of an external circuit connected to this A/D converter has an effect on conversion time (CLK frequency). See "■ TYPICAL CHARACTERISTICS".

- If the output impedance of the external input is too high, the analog voltage sampling time may be short.
- When turning the device on, turn the power supply for the digital system first before turning VREF on.

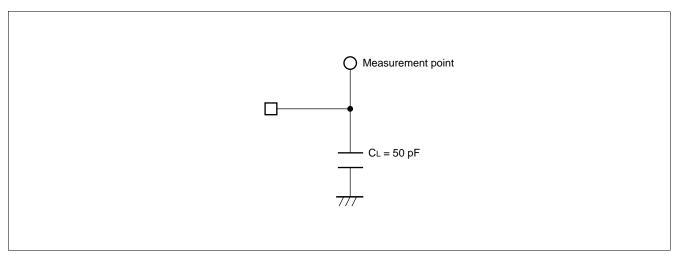
#### 2. AC Characteristics

 $(V_{REF}, V_{CC} = 3.3 \text{ V to } +5.5 \text{ V } (V_{CC} \ge V_{REF}), A_{GND} = 0 \text{ V}, Ta = -40^{\circ}\text{C to } +85^{\circ}\text{C})$ 

| Parameter                          | Symbol       | Conditions         | Value      |      | Unit     |  |
|------------------------------------|--------------|--------------------|------------|------|----------|--|
| Parameter                          | Symbol       | Conditions         | Min        | Max  | <u> </u> |  |
| Clock cycle time                   | tclk         | Vcc = 5 V ± 10% *1 | 1.0        | 30.0 | μS       |  |
| Clock cycle time                   | ICLK         | _                  | 6.0        | 30.0 | μS       |  |
| Low-level clock pulse width        | <b>t</b> ckl | _                  | 2.8        | 14.8 | μS       |  |
| High-level clock pulse width       | <b>t</b> ckH | _                  | 2.8        | 14.8 | μS       |  |
| Clock rise time<br>Clock fall time | tcr<br>tcf   | _                  | _          | 0.2  | μS       |  |
| CS setup time                      | tcss         | _                  | tckl + 0.4 | _    | μS       |  |
| CS hold time                       | <b>t</b> csH | _                  | 1.0        | _    | μS       |  |
| CS release time                    | <b>t</b> csr | _                  | 1.0        | _    | CLK      |  |
| Channel setup time                 | <b>t</b> chs | _                  | 0          | _    | μS       |  |
| Channel hold time                  | tснн         | _                  | 1.0        | _    | CLK      |  |
| Data output delay time             | tDO          | *2                 | _          | 0.5  | μS       |  |
| MOD setup time                     | tмos         | _                  | 0.2        | _    | μS       |  |
| MOD hold time                      | tмон         | _                  | 0.1        | _    | μS       |  |
| Data active delay time             | <b>t</b> dve | _                  | _          | 0.5  | μS       |  |
| Data float delay time              | <b>t</b> dze | _                  | _          | 0.5  | μS       |  |
| SAMP active delay time             | tsve         | _                  | _          | 0.5  | μS       |  |
| SAMP float delay time              | <b>t</b> sze | _                  | _          | 0.5  | μS       |  |
| SAMP high-level output delay time  | <b>t</b> shd | *2                 | _          | 0.5  | μS       |  |
| SAMP low-level output delay time   | tsld         | *2                 | _          | 0.5  | μS       |  |

<sup>\*1:</sup> Depending on the output impedance of the external circuit connected to the analog input pin

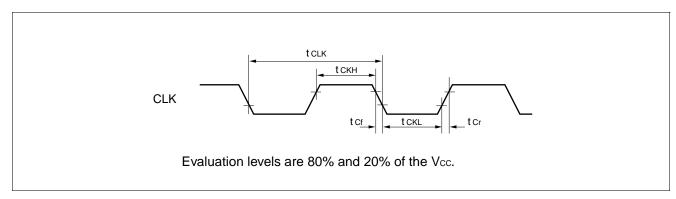
#### AC test circuit



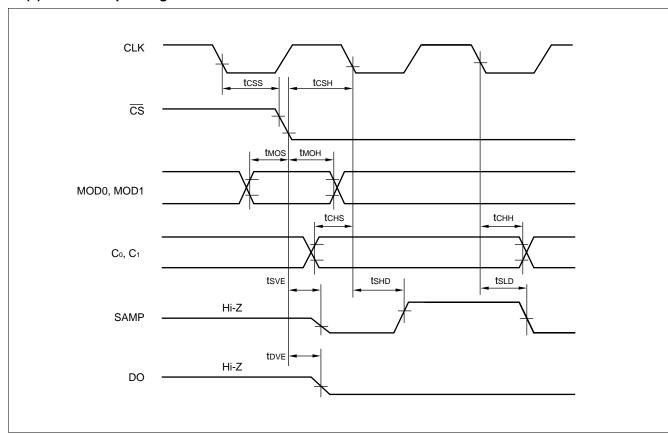
<sup>\*2:</sup> See "• AC test circuit."

### **■ TIMING DIAGRAM**

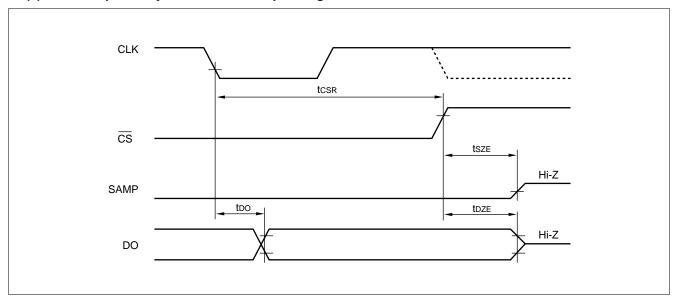
### (1) Input clock timing



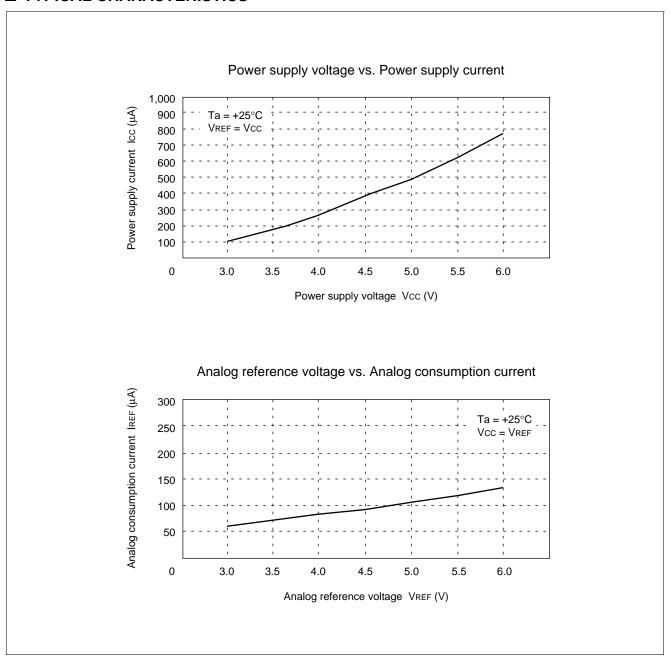
### (2) A/D startup timing



### (3) Data output delay time and A/D stop timing

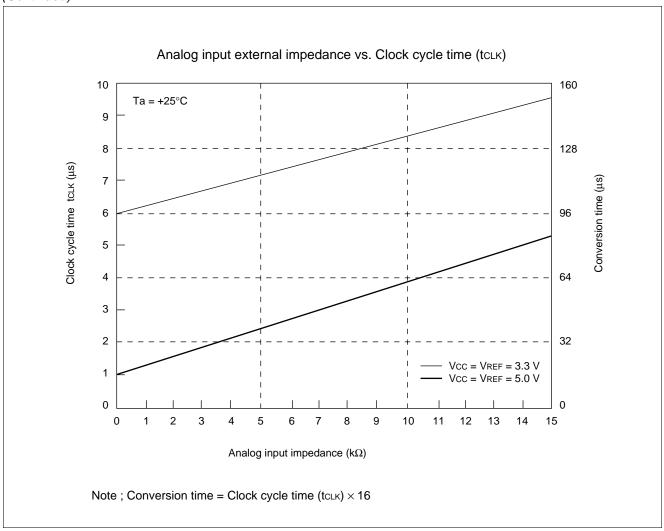


#### **■ TYPICAL CHARACTERISTICS**



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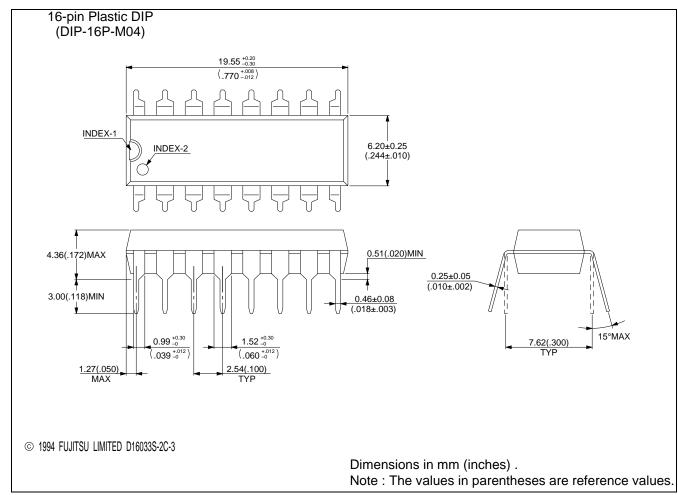
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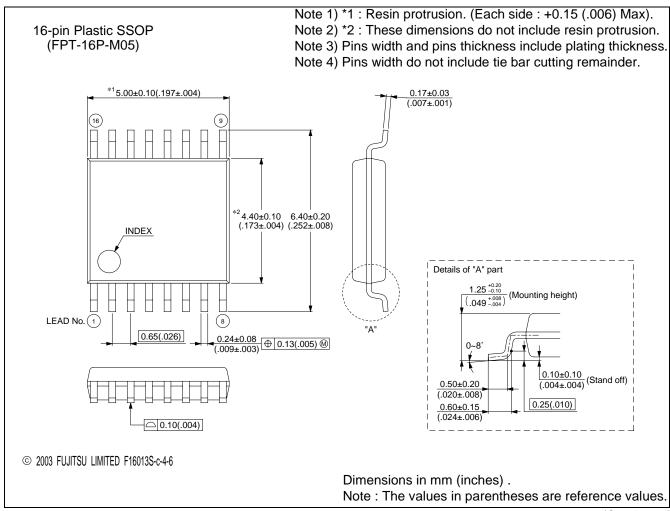
### **■ ORDERING INFORMATION**

| Part number | Package                              | Remarks |
|-------------|--------------------------------------|---------|
| MB88101AP   | 16-pin Plastic DIP<br>(DIP-16P-M04)  |         |
| MB88101APFV | 16-pin Plastic SSOP<br>(FPT-16P-M05) |         |
| MB88101APF  | 16-pin Plastic SOP<br>(FPT-16P-M06)  |         |

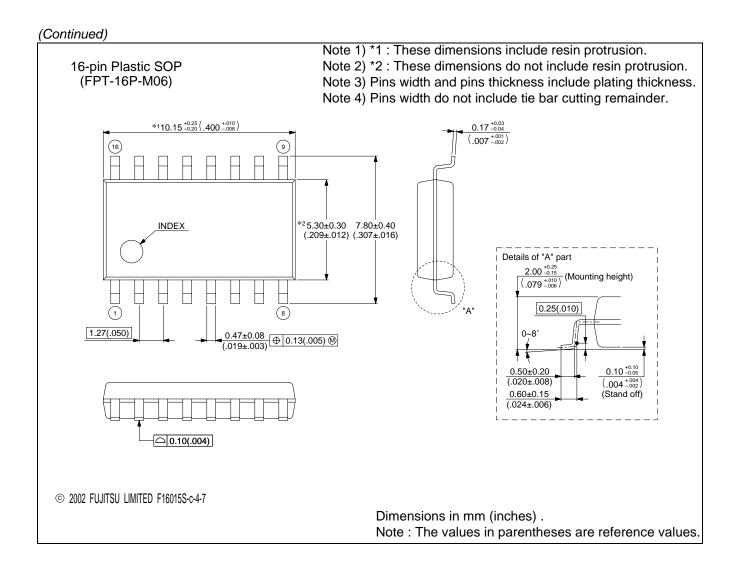
#### **■ PACKAGE DIMENSIONS**

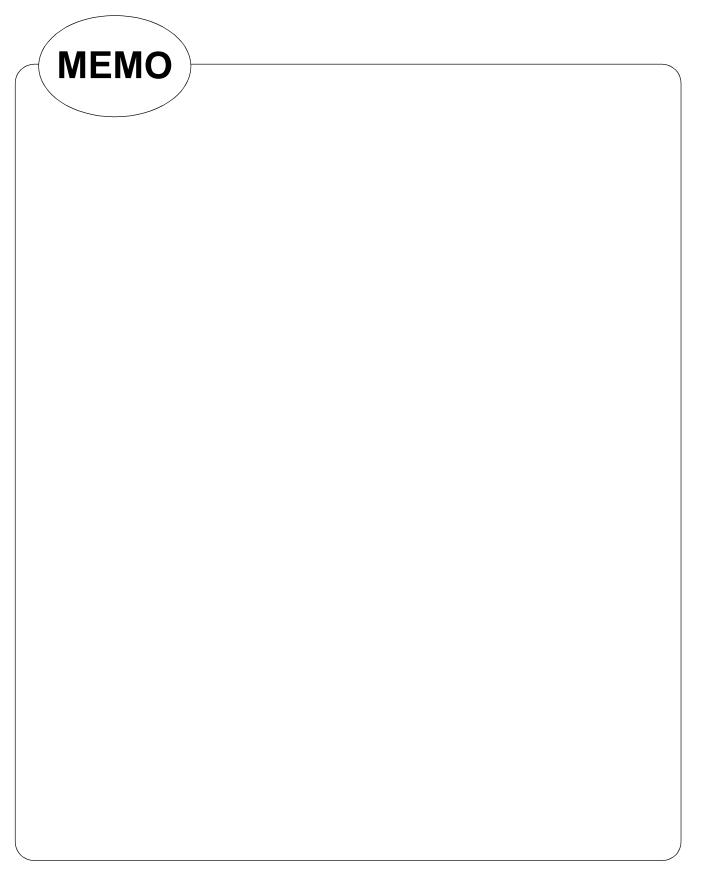


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### **FUJITSU MICROELECTRONICS LIMITED**

Shinjuku Dai-Ichi Seimei Bldg. 7-1, Nishishinjuku 2-chome, Shinjuku-ku, Tokyo 163-0722, Japan Tel: +81-3-5322-3347 Fax: +81-3-5322-3387 http://jp.fujitsu.com/fml/en/

For further information please contact:

#### North and South America

FUJITSU MICROELECTRONICS AMERICA, INC. 1250 E. Arques Avenue, M/S 333
Sunnyvale, CA 94085-5401, U.S.A.
Tel: +1-408-737-5600 Fax: +1-408-737-5999
http://www.fma.fujitsu.com/

#### Europe

FUJITSU MICROELECTRONICS EUROPE GmbH Pittlerstrasse 47, 63225 Langen, Germany Tel: +49-6103-690-0 Fax: +49-6103-690-122 http://emea.fujitsu.com/microelectronics/

#### Korea

FUJITSU MICROELECTRONICS KOREA LTD. 206 KOSMO TOWER, 1002 Daechi-Dong, Kangnam-Gu,Seoul 135-280 Korea

Tel: +82-2-3484-7100 Fax: +82-2-3484-7111

http://www.fmk.fujitsu.com/

#### Asia Pacific

FUJITSU MICROELECTRONICS ASIA PTE LTD.

151 Lorong Chuan, #05-08 New Tech Park,
Singapore 556741

Tel: +65-6281-0770 Fax: +65-6281-0220

http://www.fujitsu.com/sg/services/micro/semiconductor/

FUJITSU MICROELECTRONICS SHANGHAI CO., LTD. Rm.3102, Bund Center, No.222 Yan An Road(E), Shanghai 200002, China
Tel: +86-21-6335-1560 Fax: +86-21-6335-1605 http://cn.fujitsu.com/fmc/

FUJITSU MICROELECTRONICS PACIFIC ASIA LTD.
10/F., World Commerce Centre, 11 Canton Road
Tsimshatsui, Kowloon
Hong Kong
Tel: +852-2377-0226 Fax: +852-2376-3269
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